

### **Product Summary**

Device	BVDSS	Rds(ON) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
01	60)/	1.7Ω @ V <sub>GS</sub> = 10V	480mA
QI	Q1 60V	3Ω @ V <sub>GS</sub> = 4.5V	360mA
Q2	601/	4Ω @ V <sub>GS</sub> = -10V	-320mA
Q2	-60V	6Ω @ V <sub>GS</sub> = -4.5V	-260mA

# **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General-purpose interfacing switches
- Power management functions
- Analog switches



Top View

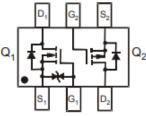




- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: SOT563 •
- Package Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.027 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Backage	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMC62D2SV-7	SOT563	3,000	Tape & Reel	
DMC62D2SV-13	SOT563	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

### **Marking Information**

	C	D	2	Y	М	
•						

CD2 = Product Type Marking Code

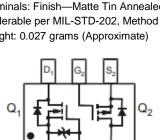
- YM = Date Code Marking
- $\overline{Y}$  = Year (ex: K = 2023)

M = Month (ex: 9 = September)

#### Date Code Kev

Notes:

Date Code Rey												
Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	Т	U	V
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		•	•		-	•	-	•	0	<u>^</u>	Ν	





# Maximum Ratings N-CHANNEL – Q1 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	480 380	mA
Maximum Body Diode Forward Current (Note 5)			ls	480	mA
Pulsed Drain Current (Note 5)			I <sub>DM</sub>	1.3	А
Pulsed Source Current (Note 5)			lsм	1.3	А

# Maximum Ratings P-CHANNEL – Q2 (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-60	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5) $V_{GS}$ = -10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-320 -250	mA
Maximum Body Diode Forward Current (Note 5)			ls	-320	mA
Pulsed Drain Current (Note 5)			I <sub>DM</sub>	-1	A
Pulsed Source Current (Note 5)			I <sub>SM</sub>	-1	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	261	°C/W
Total Power Dissipation (Note 5)		PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	158	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



# Electrical Characteristics N-CHANNEL – Q1 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			•			-
Drain-Source Breakdown Voltage	BVDSS	60		_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_		1.0	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
Gate-Source Leakage	Igss	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	1.0	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Proven	_	1.0	1.7	Ω	$V_{GS} = 10V, I_D = 200mA$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	1.2	3	12	$V_{GS} = 4.5V, I_D = 200mA$
Diode Forward Voltage	Vsd	—	0.85	1.4	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	41	—	pF	
Output Capacitance	Coss	_	4.5	_	pF	−V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V −f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	2.7	_	pF	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	0.51	—	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	1.04	—	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 200mA
Gate-Source Charge	Qgs	_	0.16	_	nC	$v_{DS} = 15 v, I_D = 200 IIIA$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.18	_	nC	
Turn-On Delay Time	td(on)	—	6.9	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	5.8	—	ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V
Turn-Off Delay Time	tD(OFF)	_	37.8	_	ns	$R_G = 150\Omega, I_D = 200mA$
Turn-Off Fall Time	tF	_	14.3	_	ns	
Reverse Recovery Time	t <sub>RR</sub>	_	19	—	ns	$I_F = 1A$ , dI/dt = 100A/µs
Reverse Recovery Charge	Qrr	_	9	_	nC	I <sub>F</sub> = 1A, dl/dt = 100A/µs

# Electrical Characteristics P-CHANNEL – Q2 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

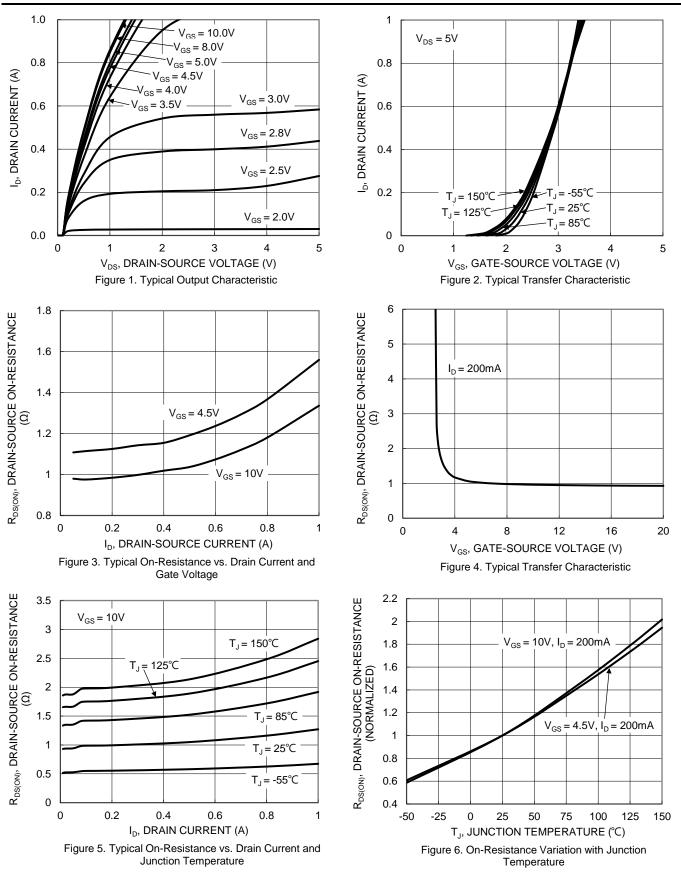
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				•	•		
Drain-Source Breakdown Voltage	BVDSS	-60		_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_		-1.0	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1	—	-3	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Ppo(ati)	_	1.8	4	Ω	$V_{GS} = -10V, I_{D} = -200mA$	
Static Drain-Source On-Resistance	Rds(on)	—	2.3	6	12	$V_{GS} = -4.5V, I_{D} = -200mA$	
Diode Forward Voltage	Vsd	—	-0.8	-1.4	V	Vgs = 0V, Is = -115mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	40	—	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	—	5	—	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	—	3	_	pF		
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	—	0.5	_	nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	—	1.1	_	nC	V <sub>DS</sub> = -10V, I <sub>D</sub> = -0.1A	
Gate-Source Charge	Qgs	—	0.1	_	nC	VDS = -10V, ID = -0.1A	
Gate-Drain Charge	$Q_gd$	—	0.1	_	nC		
Turn-On Delay Time	td(on)	—	4	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	4	_	ns	VDD = -30V, VGS = -10V	
Turn-Off Delay Time	tD(OFF)	_	39.7	_	ns	$R_G = 50\Omega, I_D = -270 mA$	
Turn-Off Fall Time	tF	_	13.8	—	ns		
Body Diode Reverse Recovery Time	trr	—	26.6	—	ns	IF = -1A, dI/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	16.3	_	nC	IF = -1A, dI/dt = 100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.

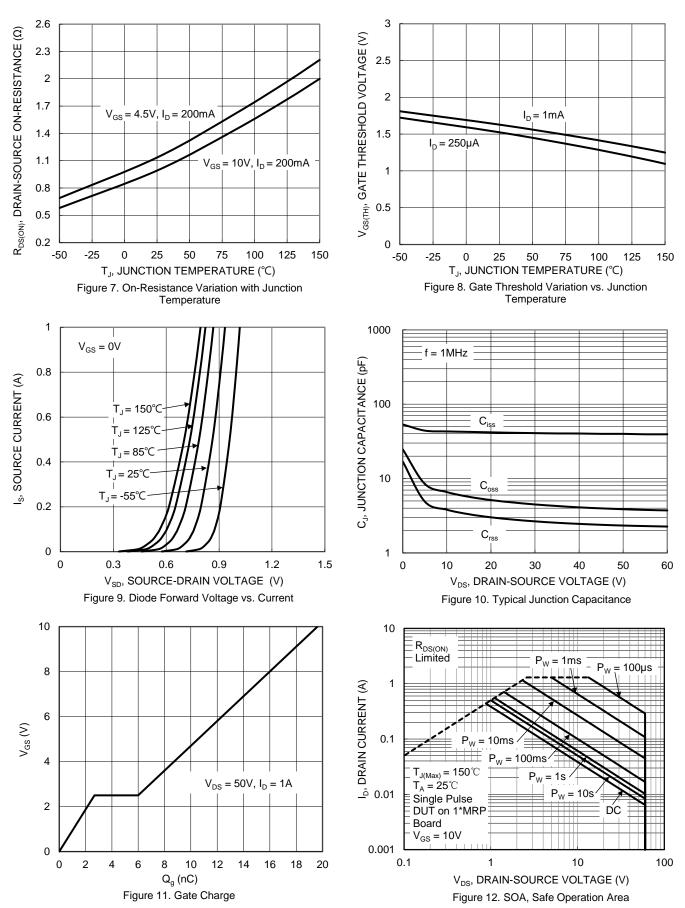
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#### N-CHANNEL - Q1



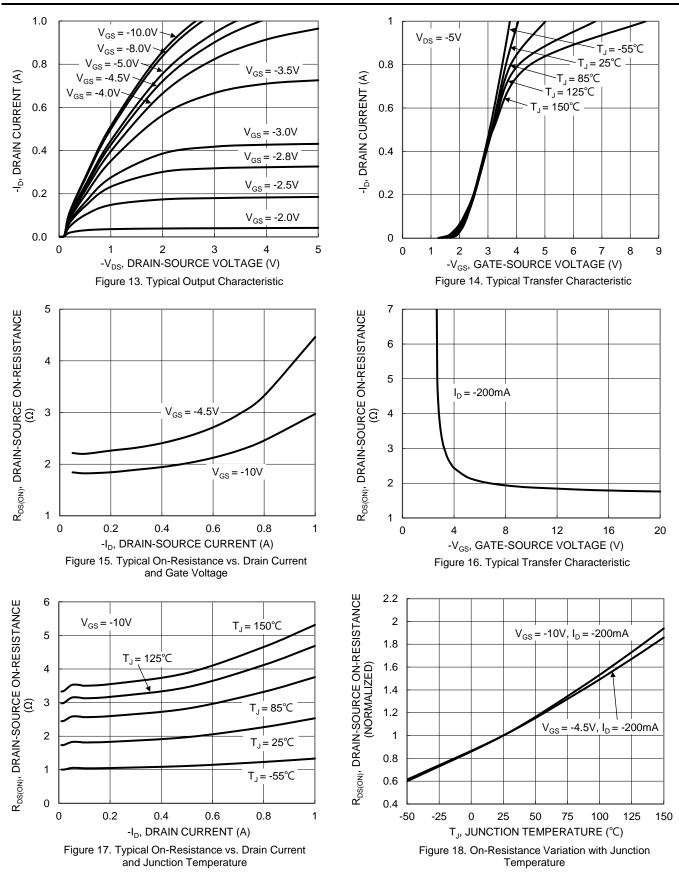




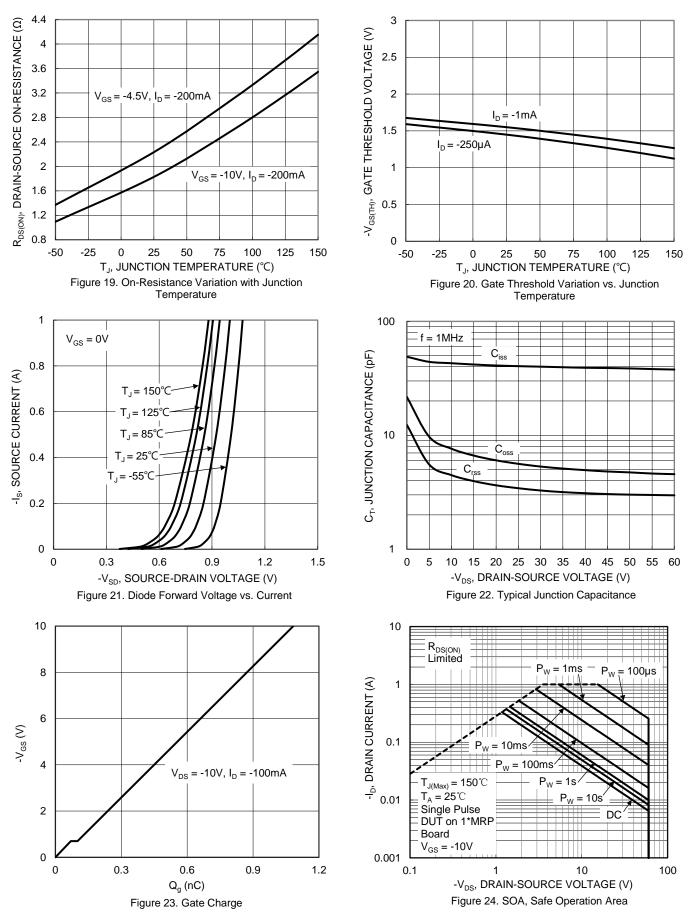
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### P-CHANNEL - Q2

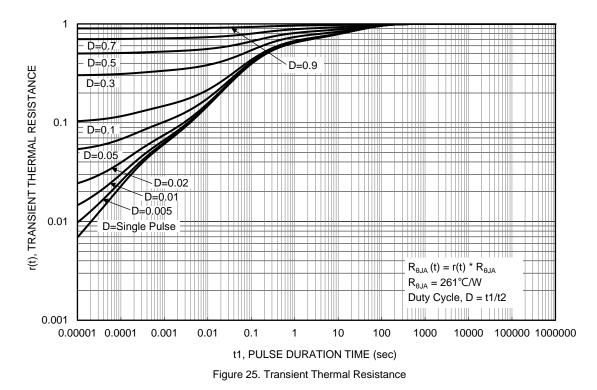






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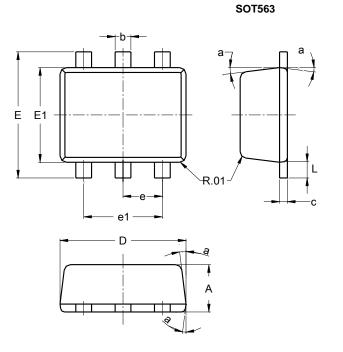






## **Package Outline Dimensions**

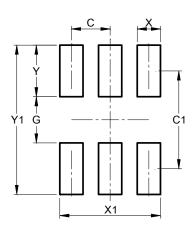
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563								
Dim	Min	Max	Тур					
Α	0.55	0.60						
b	0.15	0.30	0.20					
С	0.10	0.18	0.11					
D	1.50	1.70	1.60					
Е	1.55	1.70	1.60					
E1	1.10	1.25	1.20					
е			0.50					
e1	0.90	1.10	1.00					
L	0.10	0.30	0.20					
а	8°	9°	7°					
All	Dimens	sions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Y	0.670
Y1	1.940

#### SOT563



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